SKiM 400GD126DM



IGBT Modules

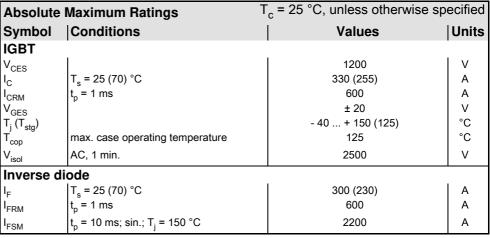
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Features

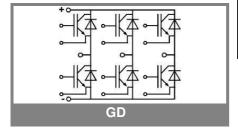
- Trench gate IGBT with field stop layer
- · Low inductance case
- Fast & soft inverse CAL diodes
- Isolated by AIN DCB (Direct Copper Bonded) ceramic plate
- Pressure contact technology for thermal contacts
- Spring contact system to attach driver PCB to the control terminals
- Integrated temperature sensor

Typical Applications*

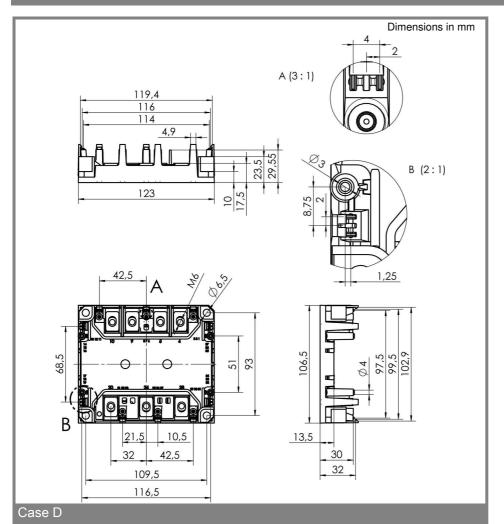
- Switched mode power supplies
- Three phase inverters for AC motor speed control
- Switching (not for linear use)

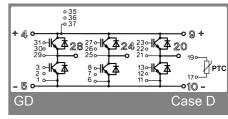


Characte	ristics	= 25 °C, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
$V_{GE(th)}$	$V_{GE} = V_{CE}$; $I_C = 12 \text{ mA}$	4,95	5,8	6,55	V
I _{CES}	$V_{GE} = 0; V_{CE} = V_{CES};$ $T_i = 25 °C$			4,4	mA
V_{CEO}	T _j = 25 (125) °C		1 (0,9)	1,2 (1,1)	V
r_{CE}	T _j = 25 (125) °C		2,3 (3,7)	3 (4,5)	mΩ
V_{CEsat}	$I_{Cnom} = 300 \text{ A}; V_{GE} = 15 \text{ V},$		1,7 (2)	2,15 (2,45)	V
	$T_j = 25 (125)$ °C on chip level				
C _{ies}	V _{GE} = 0; V _{CE} = 25 V; f = 1 MHz		23		nF
C _{oes}	$V_{GE} = 0$; $V_{CE} = 25 \text{ V}$; $f = 1 \text{ MHz}$		1,6		nF
C _{res}	$V_{GE} = 0$; $V_{CE} = 25 \text{ V}$; $f = 1 \text{ MHz}$		1,6		nF
L _{CE}				15	nΗ
R _{CC'+EE'}	resistance, terminal-chip T _c = 25 (125) °C		1,35 (1,75)		mΩ
t _{d(on)}	V _{CC} = 600 V				ns
t _r	I _{Cnom} = 300 A				ns
$t_{d(off)}$	$R_{Gon} = R_{Goff} = \Omega$				ns
t _f	T _j = 125 °C				ns
$E_{on} (E_{off})$	V _{GE} ± 15 V		29 (46)		mJ
$E_{on}\left(E_{off}\right)$	with SKHI 64; T _j = 125 °C				mJ
	V _{CC} = 600 V; I _C = 300 A				
Inverse diode					
$V_F = V_{EC}$	I _{Fnom} = 200 A; V _{GE} = 0 V; T _i = 25 (125) °C		2 (1,8)	2,55 (2,3)	V
V_{TO}	T _i = 25 (125) °C		1,1	1,45 (1,25)	V
r _T	T _j = 25 (125) °C		4,5	5,3 (5,3)	mΩ
I_{RRM}	I _F = 300 A; T _j = 125 °C				Α
Q_{rr}	V _{GE} = V di/dt = A/µs				μC
E _{rr}	R _{Gon} = R _{Goff} =				mJ
Thermal characteristics					
$R_{th(j-s)}$	per IGBT			0,134	K/W
$R_{th(j-s)}$	per FWD			0,19	K/W
	ture Sensor				
R _{TS}	T = 25 (100) °C		1 (1,67)		kΩ
tolerance	T = 25 (100) °C		3 (2)		%
Mechanic	cal data				
M ₁	to heatsink (M5)	2		3	Nm
M_2	for terminals (M6)	4		5	Nm
w				310	g
					i



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This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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